

FORM PTO-1449 (Modified)

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SERIAL NO.

YOR920000344US1

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LIST OF PATENTS AND PUBLICATIONS
FOR APPLICANT'S INFORMATION
DISCLOSURE STATEMENT

APPLICANT: Chu et al.

JAN 04 2002

FILING DATE:

Oct. 19, 2000

GROUP:

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIALS		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPRO.)
Ek	AA	5,906,951	May 1999	Chu et al.	438	751	
Ek	AB	5,476,813	Dec. 1995	Naruse	438	311	
Ek	AC	5,462,883	Oct. 1995	Dennard et al.	438	459	
Ek	AD	5,659,187	Aug. 1997	Legoues et al.	257	190	
Ek	AE	5,298,452	Mar. 1994	Meyerson	437	81	
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
	AL							
	AM							
	AN							
	AO							
	AP							

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

Ek	AQ	T. Mizuno, "High Performance Strained-Si p-MOSFET's on SiGe-On-Insulator Substrates fabricated by SIMOX Technology", IEDM Tech. Digest 99-934, 1999.						
	AR							
	AS							
	AT							
	AU							

EXAMINER

Eric K. Kober

DATE CONSIDERED

1/29/02

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.